AiT Semiconductor Inc. www.ait-ic.com

## DESCRIPTION

The A7312 is a high efficiency current-mode asynchronous, 24V/1.2A buck converter. Its input voltage ranges from 4V to 24V and it provides an adjustable regulated output voltage from 0.81V to 5.5V while delivering up to 1.2A of output current.

The switching frequency is set to 1.4MHz, which works with a inductor as small as 4.7uH. And the A7312 will automatically switch between PFM and PWM mode based on the load current, thus to enhance the converter efficiency at light load.

A7312 consists of many protection blocks such as UVLO, input voltage over voltage protection to stand much higher input voltage spike, thermal protection and output short circuit protection.

The A7312 is available in SOT-26 package.

### **ORDERING INFORMATION**

Package Type	Part Number		
SOT 26	E6	A7312E6R	
SOT-26		A7312E6VR	
Noto	V: Halogen free Package		
Note	R: Tape & Reel		
AiT provides all RoHS products			
Suffix " V " means Halogen free Package			

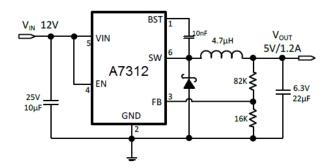
### FEATURES

- Adjustable Output Voltage, V<sub>FB</sub>=0.81V
- Output current is up to 1.2A
- Range of operation input voltage: 4~24V
- Input voltage UVLO: 3.7V (voltage decreasing)
- Input Overvoltage Protection @26V
- Withstand input voltage spike >30V
- Operating current at zero load: 0.8mA (typ.)
- Line regulation: 0.1%/V (typ.)
- Load regulation: 10mV (typ.)
- High efficiency, up to 90%
- Environment Temperature: -20°C ~85°C
- Available in SOT-26 Package

### APPLICATION

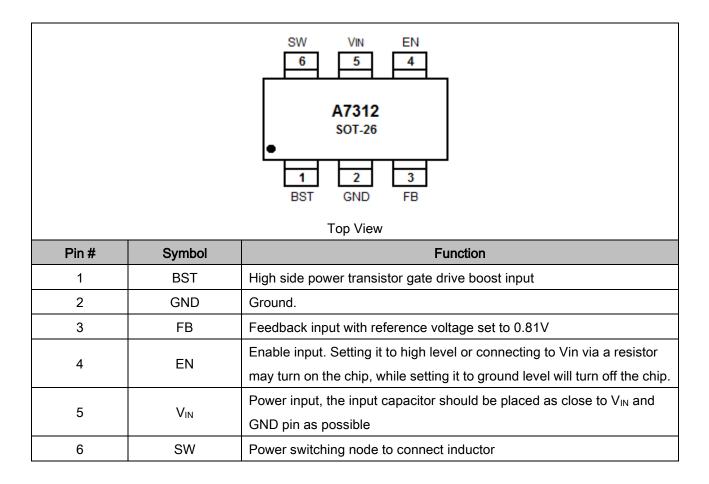
- Security Camera
- Consumer Electronic Device for automobile
- Portable DVD
- ADSL Modem, WLAN router
- Other 12V or double cell Li-ion battery powered device

## TYPICAL APPLICATION





## PIN DESCRIPTION





## ABSOLUTE MAXIMUM RATINGS

Max Input Voltage		30V
T <sub>J</sub> , Max Operating Junction Temperature		125°C
T <sub>A</sub> , Ambient Temperature		-20°C ~ 85°C
Package Thermal Resistance	SOT-26 (θ <sub>JC</sub> )	110°C / W
	SOT-26 (θ <sub>JA</sub> )	220°C / W
Ts, Storage Temperature		-40°C ~150°C
Lead Temperature & Time		260°C, 10S
HBM, ESD		>2KV

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN	MAX	Units
Input Voltage Range		4	24	V
Output Voltage Range		0.81	5.5	V
Operating Junction Temperature	TJ	-20	125	°C



# ELECTRICAL CHARACTERISTICS

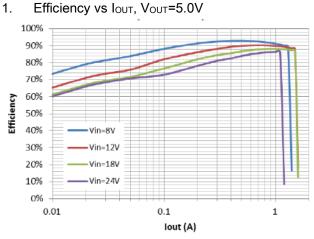
V<sub>IN</sub>=12V, T<sub>A</sub>=25°C

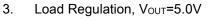
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Voltage Range	V <sub>DD</sub>		4		24	V
Output Voltage Range	Vout		0.81		5.5	V
Feedback Voltage	Vref	V <sub>IN</sub> =12V, V <sub>EN</sub> =5V	0.79	0.81	0.83	V
UVLO Voltage	Vuvlo	V <sub>IN</sub> H>L, I <sub>OUT</sub> =0.5A		3.7		V
Feedback Leakage Current	lfb			0.1	0.4	uA
Quiescent Quirrent		Active, V <sub>FB</sub> =1V, No Switching		0.6	1.0	mA
Quiescent Current	lq	Shutdown, V <sub>IN</sub> =8V		6	10	uA
Line Regulation	LnReg	V <sub>IN</sub> =5V to 12V		0.1		%/V
Load Regulation	LdReg	I <sub>OUT</sub> =0.1 to 1.2A		0.02		%/A
Switching Frequency	Fsoc	V <sub>EN</sub> =3V, V <sub>IN</sub> =12V	1.0	1.4	1.8	MHz
High side Switch RDSON	RDSON_H	Isw=200mA		250	350	mohm
Peak Inductor Current Limit	ILIMIT	V <sub>IN</sub> =12V, V <sub>OUT</sub> =5V	1.5	2		А
EN High Threshold	V <sub>EN_H</sub>		1	1.5	3	V
EN Low Threshold	$V_{\text{EN}\_\text{L}}$				0.5	V
Input Over-Voltage Protection	Vovp	V <sub>EN</sub> =3V		26		V
Over Temperature Protection	TSD	Hystersis=40°C		150		°C

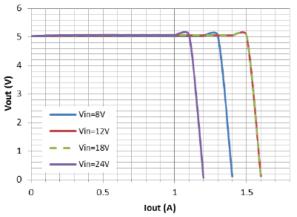


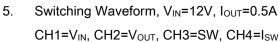
## TYPICAL PERFORMANCE CHARACTERISTICS

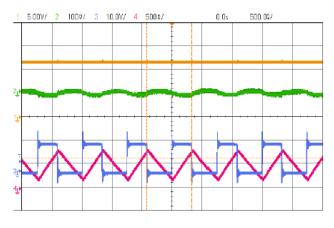
 $V_{\text{IN}}=12V, V_{\text{OUT}}=5.0V, L=4.7 uH, C_{\text{IN}}=10 uF, C_{\text{OUT}}=22 uF, T_{\text{A}}=25^{\circ}C, \text{ unless otherwise stated}$ 

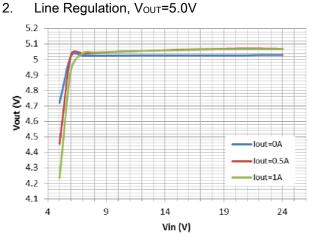




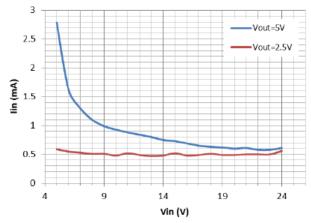




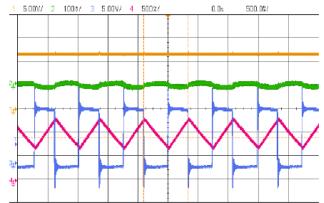




4. Input Current at Zero Load, Iout=0mA

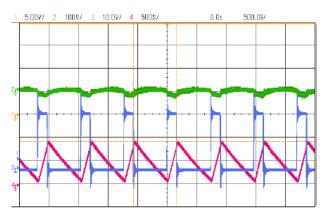


6. Switching Waveform,  $V_{IN}$ =12V,  $I_{OUT}$ =1A CH1=V<sub>IN</sub>, CH2=V<sub>OUT</sub>, CH3=SW, CH4=I<sub>SW</sub>

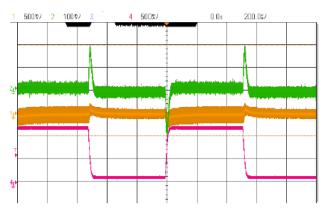




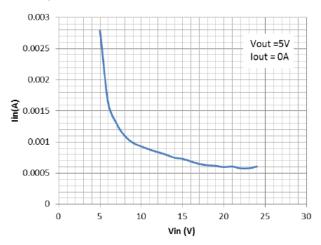
Switching Waveform, VIN=24V, IOUT=0.5A
CH1=VIN, CH2=VOUT, CH3=SW, CH4=Isw



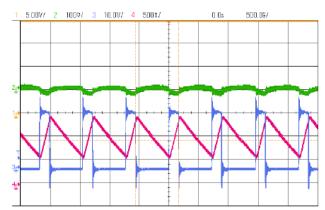
9. Load Transient Response, V<sub>IN</sub>=12V, I<sub>OUT</sub>=0.12~1A CH1=V<sub>IN</sub>, CH2=V<sub>OUT</sub>, CH4=I<sub>SW</sub>



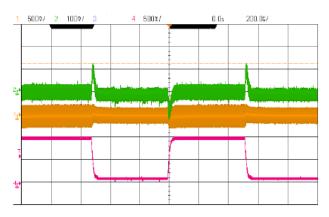
11. Input Current at Zero Load



Switching Waveform, VIN=24V, IOUT=1A
CH1=VIN, CH2=VOUT, CH3=SW, CH4=Isw

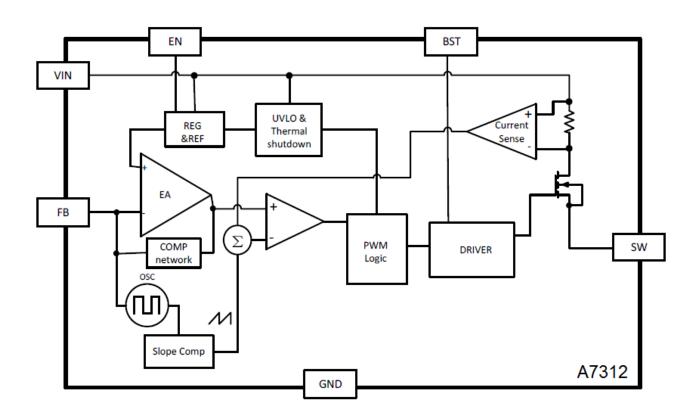


10. Load Transient Response, VIN=24V, IOUT=0.12~1A CH1=VIN, CH2=VOUT, CH4=Isw





## **BLOCK DIAGRAM**





### DETAILED INFORMATION

#### **Functional Description**

#### Loop Operation

The A7312 is a wide input range, high-efficiency, DC-to-DC step-down switching regulator, capable of delivering up to 1.2A of output current, integrated with a  $250m\Omega$  MOSFET, with external schottky diode. It uses a PWM current-mode control scheme. An error amplifier integrates error between the FB signal and the internal reference voltage. The output of the integrator is then compared to the sum of a current-sense signal and the slope compensation ramp. This operation generates a PWM signal that modulates the duty cycle of the power MOSFETs to achieve regulation for output voltage.

### **Current Limit**

There is a cycle-by-cycle current limit on the high-side MOSFET of 1.5A (typ). When the current flowing out of SW exceeds this limit, the high-side MOSFET turns off and the external schottky diode rectifier turns on. Unlike the traditional method of current limiting by limiting the voltage at the internal compensation node, which usually has large variation due to duty cycle variance, this type of peak current limiting scheme provides a relatively more accurate limit for output current, thereby lowering the requirements for system design.

#### **Light Load Operation**

Traditionally, a fixed current mode constant frequency PWM DC-DC regulator always switches even when the output load is small. When energy is shuffling back and forth through the power MOSFETs, power is lost due to the finite RDSONs of the MOSFETs and parasitic capacitances. At light load, this loss is prominent and efficiency is therefore very low. A7312 employs a proprietary control scheme that improves efficiency in this situation by enabling the device into a power save mode during light load, thereby extending the range of high efficiency operation.

#### **Component Selection**

When setting up the A7312 for different output voltage, please use following recommended component value for the best performance.

Vout (V)	Cουτ(μF)	L(µH)
5.0	22	6.8~10
3.3	22	4.7~10
2.5	22	3.3~10



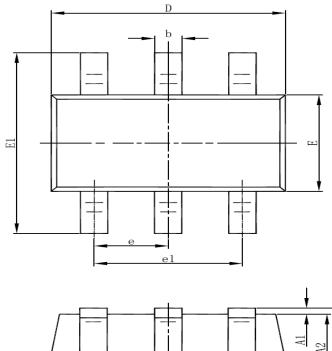
### **Thermal Consideration**

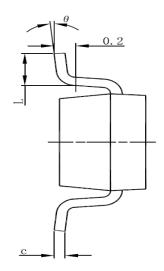
A7312 is high efficiency Buck converter, which means it consumes very few power when converting the high voltage to low voltage. However, when output power is very large, like 5V/1.2A, the output power is as high as 6W, a heat dissipation path is strongly recommended to be routed on PCB. A7312 is in SOT-26 package. The heat is conducted out via Pin 2 (GND), so the heat dissipation route on PCB should be connected to the Pin 2 of the chip.

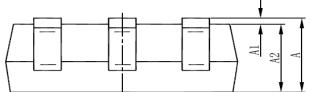


# PACKAGE INFORMATION

Dimension in SOT-26 Package (Unit: mm)







SYMBOL	MIN	MAX	
А	1.100	1.400	
A1	0.000	0.100	
A2	1.000	1.300	
b	0.200	0.500	
с	0.100	0.250	
D	2.700	3.100	
E	1.500	1.800	
E1	2.500	3.100	
е	0.950(BSC)		
e1	1.700	2.100	
L	0.200	-	
θ	0°	8°	



## IMPORTANT NOTICE

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